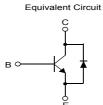


FJD5304D High Voltage Fast Switching Transistor

Features

- Built-in Free Wheeling Diode
- Wide Safe Operating Area
- Small Variance in Storage Time
- Suitable for Electronic Ballast Application





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CBO}	Collector-Base Voltage	700	V	
V _{CEO}	Collector-Emitter Voltage	400	V	
V _{EBO} Emitter-Base Voltage		12	V	
I _C	Collector Current (DC)	4	A	
I _{CP}	* Collector Current (Pulse)	8	A	
I _B	Base Current (DC)	2	A A W °C	
I _{BP}	* Base Current (Pulse)	4		
P _C	Collector Dissipation ($T_C = 25^{\circ}C$)	30		
TJ	Junction Temperature	150		
T _{STG}	Storage Temperature	-55 ~ 150	°C	

* Pulse Test: PW = $300\mu s$, Duty Cycle = 2% Pulsed

Package Marking and Ordering Information

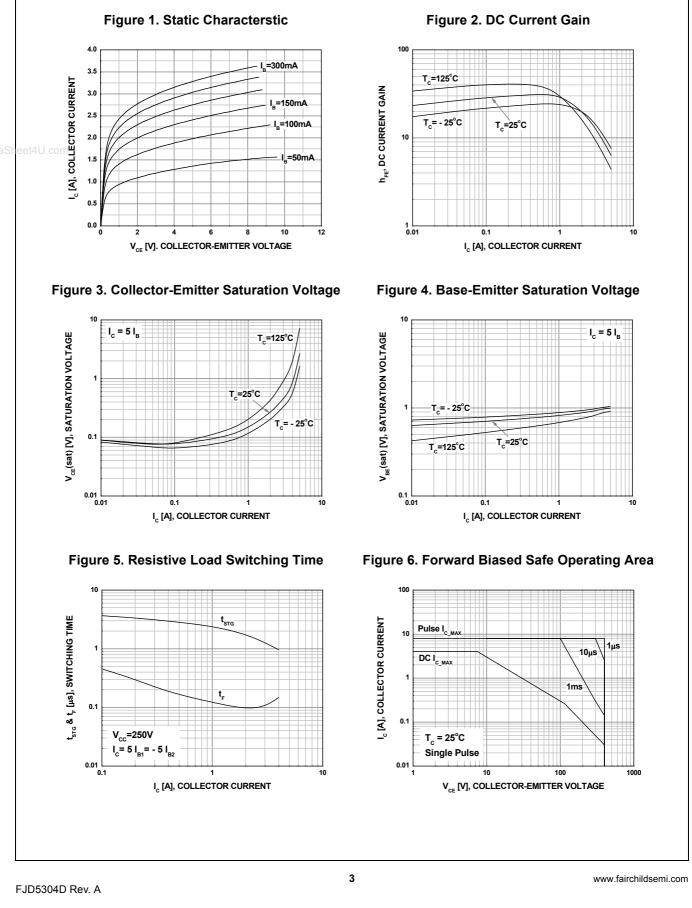
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
J5304D	FJD5304DTM	D-PAK	13" Dia	-	2500
J5304D	FJD5304DTF	D-PAK	13" Dia	-	2000

FJD5304D
High
Voltage
Fast
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Transistor

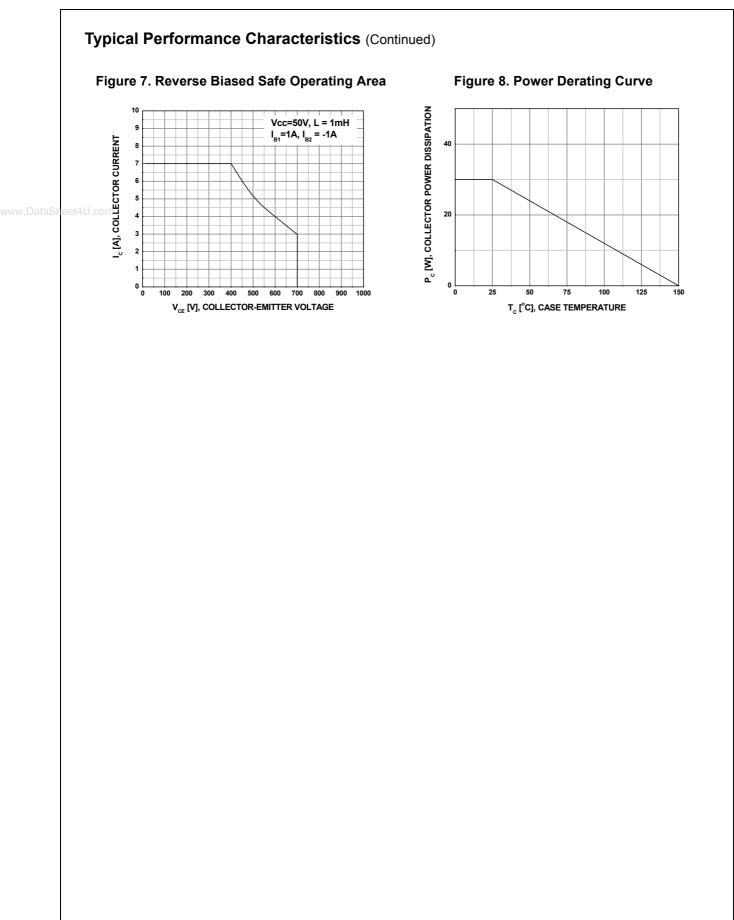
Symbol	Parameter	Conditions	Min.	Тур.	Max	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C = 1mA, I _E = 0	700			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 5mA, I _B = 0	400			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA, I _C = 0	12			V
I _{CES}	Collector Cut-off Current	V _{CB} = 700V, I _E = 0			100	μA
I _{CEO}	Collector Cut-off Current	V _{CB} = 400V, I _B = 0			250	μA
I _{EBO}	Emitter Cut-off Current	V _{EB} = 12V, I _C = 0			1	mA
h _{FE} J.com	DC Current Gain	$V_{CE} = 5V, I_C = 10mA$ $V_{CE} = 5V, I_C = 2.0A$	10 8		40	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 0.5A, I _B = 0.1A			0.7	V
		I _C = 1.0A, I _B = 0.2A			1.0	V
		I _C = 2.5A, I _B = 0.5A			1.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 0.5A, I _B = 0.1A			1.1	V
		I _C = 1.0A, I _B = 0.2A			1.2	V
		I _C = 2.5A, I _B = 0.5A			1.3	V
t _{STG}	Storage Time	V _{CLAMP} =200V, I _C =2.0A		0.6		μS
t _F	Fall Time	I _{B1} =0.4A, V _{BE} (off)=-5V, L=200μH		0.1		μS
t _{STG}	Storage Time	V _{CC} =250V, I _C =2.0A			2.9	μS
t _F	Fall Time	I _{B1} =0.4A, I _{B2} =-0.4A, T _P =30μs		0.2		μS

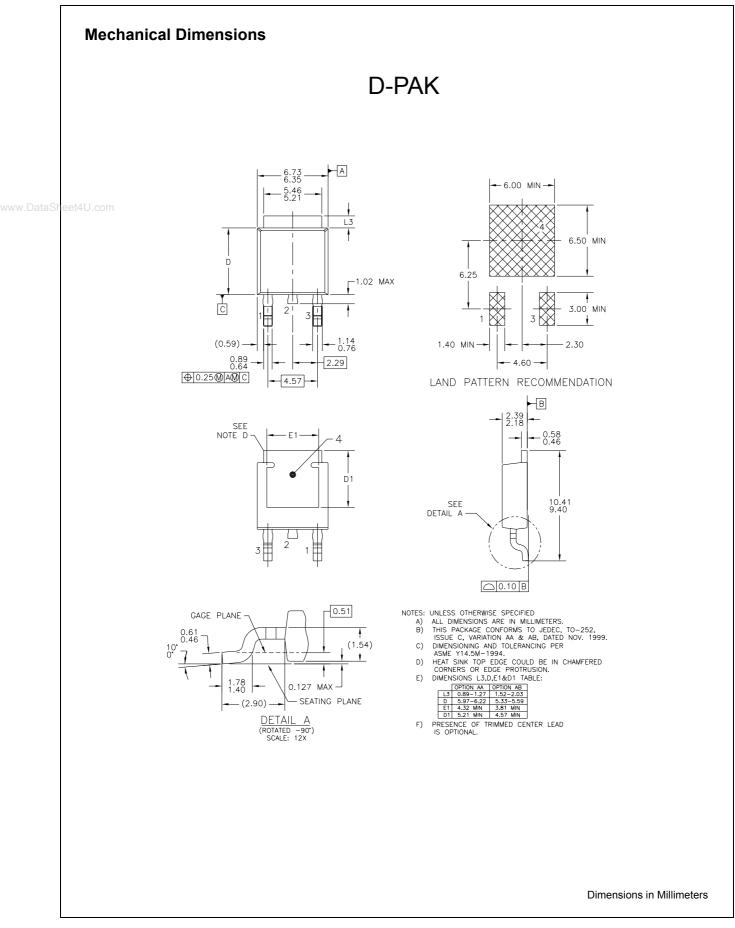
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FJD5304D High Voltage Fast Switching Transistor



Typical Performance Characteristics





FJD5304D High Voltage Fast Switching Transistor

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